

20A 45V LOW VF SchottkyBarrierDiode

1 Description

Dual center tab Schottky rectifier suited for High Frequency server and telecom base station SMPS. Packaged in TO Inside the package, this device combineshigh current rating and low volume to enhance both reliability and power density of the application.

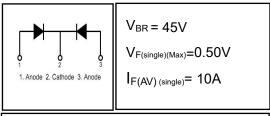
TO-220F provides insulation voltage rated at 2000V RMS from all three terminals to external heatsink.

2 Features

- High junction temperature capabiliy
- Low leakage current
- Low thermal resistance
- High frequency operation
- Avalanche specification

3 Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose





4 Electrical Characteristics

4.1 Absolute Maximum Ratings (Tc=25°C,unless otherwise noted)

PARAMETER			SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage			V_{RRM}	45	V
RMS Reverse Voltage			V _{R(RMS)}	31	V
DC Blocking Voltage			V _R	45	V
Average Rectified Forward Current(single)	TO-220F,Tc=90°C TO-220/263/3P,Tc=120°C			10	Α
Average Rectified Forward Current(double)			I _{F(AV)}	20	Α
Repetitive Peak Surge Current(single)	Repetitive Peak Surge Current(single)		I _{FRM}	20	Α
Nonrepetitive Peak Surge Current(single)	t=	=8.3ms	I _{FSM}	180	Α
Reverse Surge Current (Note 1)			I _{RSM}	8	Α
Operating Junction Temperature Range			Tj	- 55∼150	$^{\circ}$
Storage Temperature Range			T _{stg}	- 55∼150	$^{\circ}$
ESD (Machine Model=C)				>400	V
ESD (Human Body Model=3B)			>8000	V	
ESD(Noncontact)				>15000	V

4.2 Thermal Characteristics

PARAMETER	SYMBOL	VALUE				UNIT
FARAWETER	STWIDOL	To-3P TO-220 TO-263 TO-220F				
Thermal Resistance, Junction to Case-sink	R _{thJC}	0.65	1.0	0.90	2.0	°C/W



4.3 Electrical Characteristics

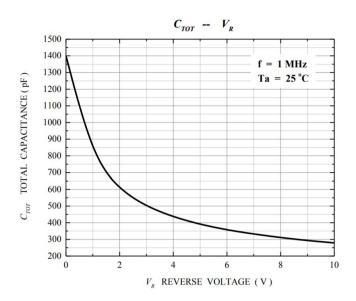
(Tc=25[°]C,unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Maximum Instantaneous	V _F	I _F = 5A	-	0.42	-	V
Forward Voltage(Note 3)		I _F = 10A	-	0.45	0.50	V
		I _F = 10A, T _C = 125°C	-	-	0.46	V
		I _F = 20A	-	0.51	0.65	V
Maximum Instantaneous	I _R	V _R = 45V	-	60	150	uA
Reverse (Note 2)		V _R = 45V, T _C = 125℃	-	-	50	mA
Total capacitance	Ctot	V _R =4V f=1MHz	-	430	-	pF
DC Blocking Voltage	V _{BR}	I _R =100uA	45	52	-	V

Notes

- 1. 2.0us Pulse Width, f=1.0 KHz
- 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
- 3. VF Instantaneous forward voltage (pw = $300\mu s$, D = 2%).

5 Typical characteristics diagrams



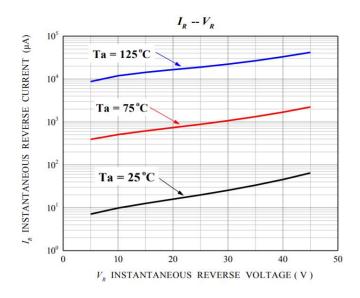


FIGURE 1. Total capacitance vs Voltage

 $I_{F} - V_{F}$ 10^{5} $Ta = 25^{\circ}C$ $Ta = 125^{\circ}C$ 10^{3} 10^{2} 10^{0} 0.0 0.1 0.2 0.3 0.4 0.5 0.6 0.7 V_{F} INSTANTANEOUS FORWARD VOLTAGE (V)

FIGURE 3. FORWARD CURRENT vs FORWARD VOLTAGE

FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

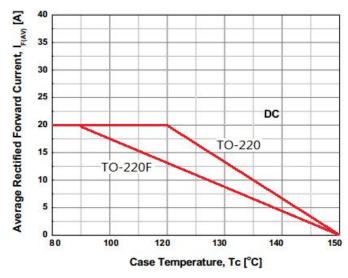
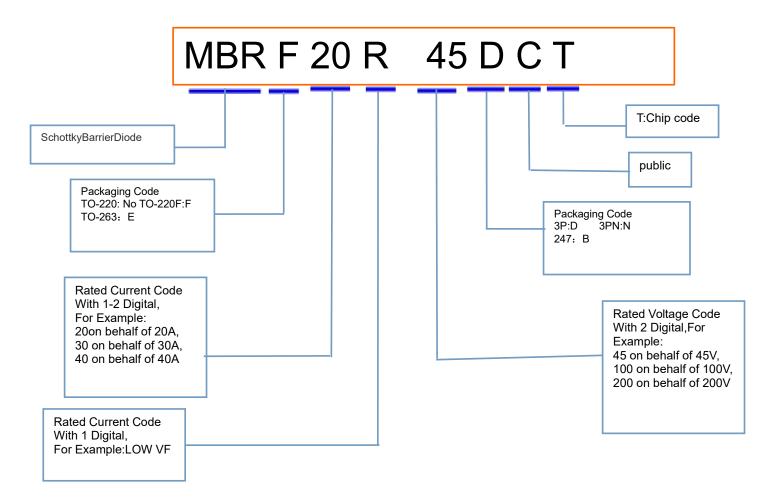


FIGURE 4. CURRENT DERATING CURVE



6 Product Names Rules



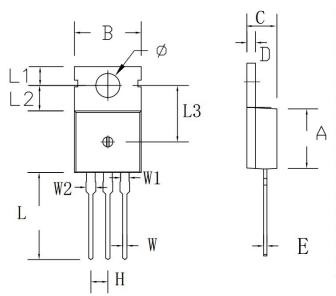
7 Product Specifications and Packaging Models

Product Model	Package Type	Mark Name	RoHS	Package	Quantity
MBR20R45CT	TO-263	MBR20R45CT	Pb-free	Braid	800/disc
MBR20R45CT	TO-220	MBR20R45CT	Pb-free	Tube	1000/box
MBR20R45DCT	TO-3P	MBR20R45DCT	Pb-free	Tube	300/box
MBRF20R45CT	TO-220F	MBRF20R45CT	Pb-free	Tube	1000/box



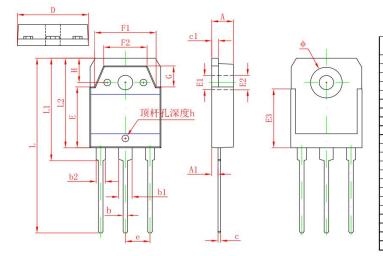
8 Dimensions

TO-220C PACKAGE OUTLINE DIMENSIONS



Crowle a 1	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
A	8. 80	9. 30	0. 346	0. 366
В	9. 70	10.30	0. 382	0.406
С	4. 25	4. 75	0. 167	0. 187
D	1. 20	1.45	0.047	0.057
Е	0.40	0.60	0.016	0.024
Н	2. 54	TYP	0.100 TYP	
W	0.60	0.95	0.024	0. 037
W1	1.05	1.45	0.041	0.057
W2	1. 20	1.60	0.047	0.063
L	12.60	13. 40	0. 496	0. 528
L1	2. 45	2.95	0.096	0.116
L2	3. 45	3. 95	0. 136	0. 156
L3	8. 15	8. 65	0. 321	0. 341
Φ	3, 50	3. 90	0. 138	0. 154

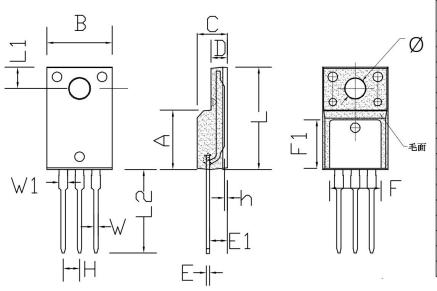
TO-3P PACKAGE OUTLINE DIMENSIONS



	Dimensions	In Millimeters	Dimension	s In Inches	
Symbol	M in	Max	M in	Max	
Α	4.600	5.000	0.181	0.197	
A 1	1.200	1.600	0.047	0.063	
b	0.800	1.200	0.031	0.047	
b 1	2.800	3.200	0.110	0.126	
b 2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.450	1.650	0.057	0.065	
D	15.450	15.850	0.608	0.624	
E	13.700	14.100	0.539	0.555	
E 1	3.200	REF	0.126 REF		
E 2	3.300 REF		0.130	REF	
E 3	13.450 REF		0.530	REF	
F 1	13.400	13.800	0.528	0.543	
F2	9.400	9.800	0.370	0.386	
L	39.900	40.300	1.571	1.587	
L1	23.200	23.600	0.913	0.929	
L2	20.300	20.600	0.799	0.811	
Φ	6.900	7.100	0.272	0.280	
G	5.150	5.550	0.203	0.219	
е	5.45	TYP	0.21	5 TYP	
Н	5.000	REF	0.197	7 REF	
h	0.000	0.300	0.000	0.012	

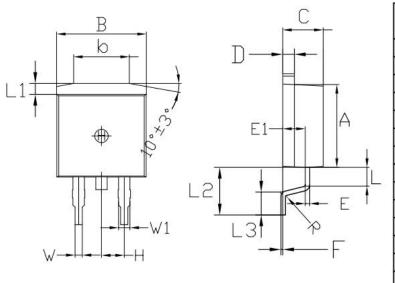


TO-220F PACKAGE OUTLINE DIMENSIONS



Symbol	DimensionsIn	Millimeters	Dimension:	sIn Inches
Syllibol	min.	max.	min.	max.
Α	8.80	9.30	0.346	0.366
В	10.00	10.50	0.394	0.413
С	4.30	4.90	0.169	0.193
D	2.30	2.70	0.091	0.106
L	15.55	16.15	0.612	0.636
h	0.40	0.60	0.016	0.024
L1	3.15	3.55	0.124	0.140
L2	12.65	13.35	0.498	0.526
W	0.70	0.90	0.028	0.035
W1	1.15	1.55	0.045	0.061
Н	2.54 TYP		0.100 TYP	
Е	0.48	0.53	0.019	0.021
ф	2.90	3.40	0.114	0.134
E1	2.40	2.90	0.094	0.114
F	7.75	8.25	0.305	0.325
F1	7 35	7.85	0.289	0.309

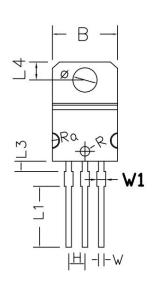
TO-263 PACKAGE OUTLINE DIMENSIONS

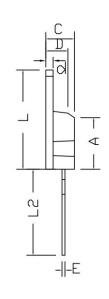


0 1 1	Dimensions I	n Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
A	8.80	9. 30	0. 346	0. 366
В	9. 70	10. 30	0. 382	0. 406
C	4. 25	4. 75	0. 167	0. 187
D	1.20	1.45	0. 047	0.057
Е	0. 40	0.60	0.016	0. 024
L	12. 25	13. 75	0. 482	0. 541
L1	1.15	1. 45	0.045	0.057
R	0. 24	0. 26	0.0095	0. 0102
W	0.80	0.82	0.0315	0. 0323
W1	1.20	1. 30	0.047	0.051
Н	2.	54 TYP	0. 200 TYP	
b	5. 50	6. 50	0. 216	0. 256
E1	2. 4	2.6	0.0946	0. 1024
L2	5. 20	5. 80	0. 205	0. 228
L3	2. 20	3. 20	0.087	0. 126
F	0. 03	0. 23	0.0012	0.0091



TO-220M PACKAGE OUTLINE DIMENSIONS





Camba 1	Dimensions I	n Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
	MIN	MAX	MIN	MAX
A	7. 55	8. 05	0. 297	0.317
В	9.85	10. 25	0. 388	0. 404
C	4. 20	4. 80	0. 165	0. 189
D	3. 20	3.60	0. 126	0.142
Е	0.42	0. 47	0.017	0.019
L	15. 20	15.60	0. 598	0.614
Н	2. 52	2. 56	0. 099	0. 101
W	0.78	0.88	0.031	0.035
Φ	3.60	3. 90	0. 142	0. 154
R	0.72	0.78	0.028	0. 031
Ra	9.00	10. 5	0.354	0.413
d	1. 10	1.40	0.043	0.055
L1	9.3	9.7	0. 366	0.382
L2	13.00	13.60	0. 512	0. 535
L3	1.20	1.70	0. 047	0.067
L4	2.60	3.0	0. 102	0. 118
W1	1.10	1.50	0.043	0.059

10 Attentions

- Jiangsu Donghai Semiconductor Co.,Ltd. reserves the right to change the specification without prior notice! The customer should obtain the latest version of the information before making the order and verify that the information is complete and up to date.
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- Product promotion is endless, our company will be dedicated to provide customers with better products.

11 Appendix

Revision history:

Date	REV.	Description	Page
2018.10.19	1.0	Original	
2022.01.01	1.1	Modify company name	all